



#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE2004NE uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications .It is ESD protested.

#### **General Features**

● V<sub>DS</sub> = 20V,I<sub>D</sub> =6A

 $R_{DS(ON)}$  < 30m $\Omega$  @  $V_{GS}$ =2.5V

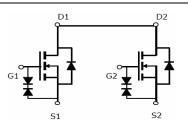
 $R_{DS(ON)}$  < 24m $\Omega$  @  $V_{GS}$ =4.5V

ESD Rating: 2000V HBM

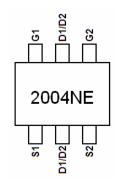
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

#### **Application**

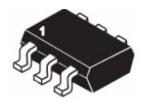
- PWM application
- Load switch



#### Schematic diagram



#### Marking and pin assignment



SOT23-6L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2004NE	NCE2004NE	SOT23-6L	Ø330mm	12mm	3000 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

7 to contact maximum readings (1.4-20 contact most motor)					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V <sub>DS</sub>	20	V		
Gate-Source Voltage	V <sub>GS</sub>	±12	V		
Drain Current-Continuous	I <sub>D</sub>	6	А		
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	30	А		
Maximum Power Dissipation	P <sub>D</sub>	1.25	W		
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}\! \mathbb{C}$		

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	100	°C/W
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# NCE2004NE

### Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	20		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V	-	-	±10	μA
On Characteristics (Note 3)			•			•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	0.45	0.7	1.0	V
During Control Control	_	V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	17	24	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =2.5V, $I_D$ =5A	-	22	30	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =6A	-	20	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	C <sub>lss</sub>	\/ 40\/\/ 0\/	-	650	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =10V, $V_{GS}$ =0V, F=1.0MHz	-	140	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIHZ	-	60	-	PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>		-	0.5		nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =10 $V$ , $R_L$ =1. $5\Omega$	-	1		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =5 $V$ , $R_{GEN}$ =3 $\Omega$	-	12		nS
Turn-Off Fall Time	t <sub>f</sub>		-	4		nS
Total Gate Charge	Qg	\/ 40\/ L 04	-	8		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=10V, I_{D}=6A,$	-	2.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =4.5V	-	3	-	nC
Drain-Source Diode Characteristics				ı		1
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =1A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	6	Α

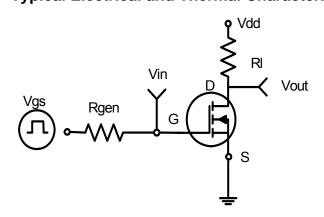
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

**Pb Free Product** 



## Typical Electrical and Thermal Characteristics



**Figure 1:Switching Test Circuit** 

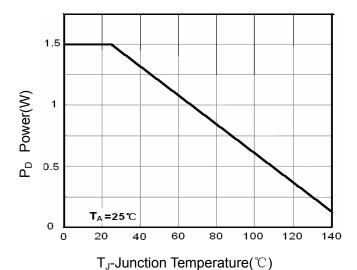


Figure 3 Power Dissipation

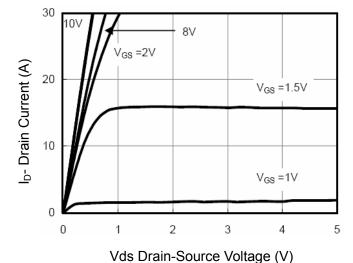


Figure 5 Output Characteristics

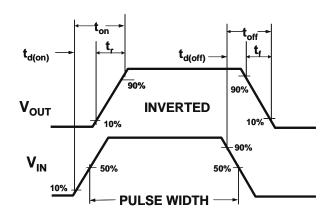
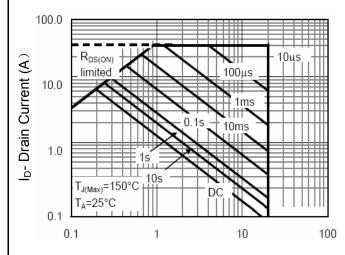


Figure 2:Switching Waveforms



Vds Drain-Source Voltage (V)

**Figure 4 Safe Operation Area** 

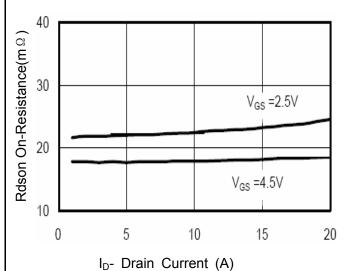
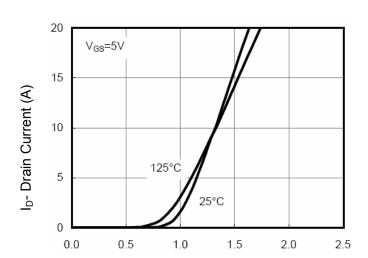


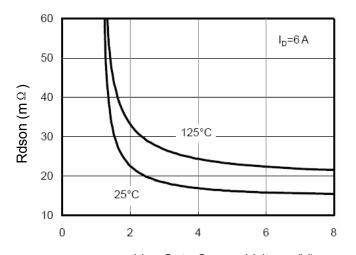
Figure 6 Drain-Source On-Resistance

**Pb Free Product** 





Vgs Gate-Source Voltage (V)
Figure 7 Transfer Characteristics



Vgs Gate-Source Voltage (V)
Figure 9 Rdson vs Vgs

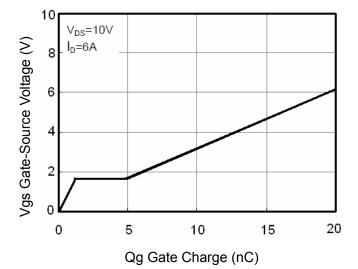


Figure 11 Gate Charge

1.6 Normalized On-Resistance O

75

0

25

50

 $T_J$ -Junction Temperature( ${}^{\circ}$ C) Figure 8 Drain-Source On-Resistance

100

125

150

175

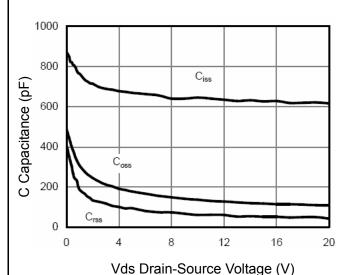
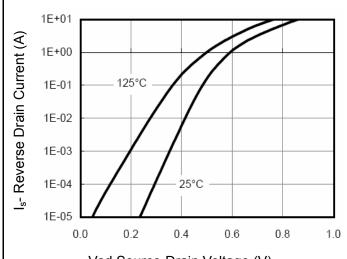


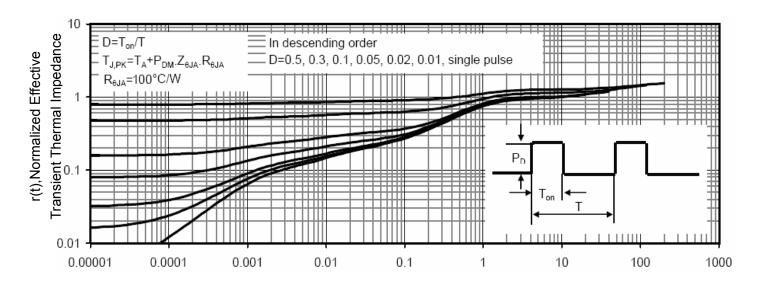
Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward



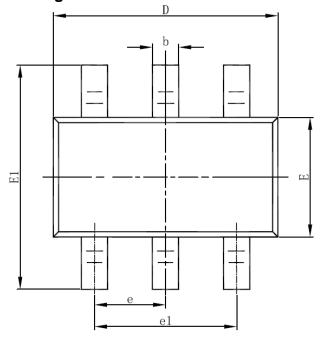


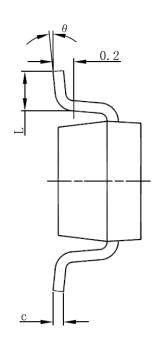
Square Wave Pluse Duration(sec)

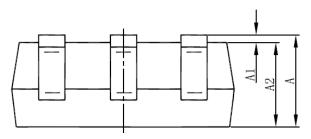
**Figure 13 Normalized Maximum Transient Thermal Impedance** 



## **SOT23-6L Package Information**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



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